



## CMST2907A

**SUPER-MINI  
PNP SILICON TRANSISTOR**

**SUPER  
mini**



**SOT-323 CASE**

# Central<sup>TM</sup>

Semiconductor Corp.

### DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMST2907A type is an PNP silicon transistor manufactured by the epitaxial planar process, epoxy molded in a super-mini surface mount package, designed for small signal general purpose and switching applications.

### MAXIMUM RATINGS: ( $T_A=25^{\circ}\text{C}$ )

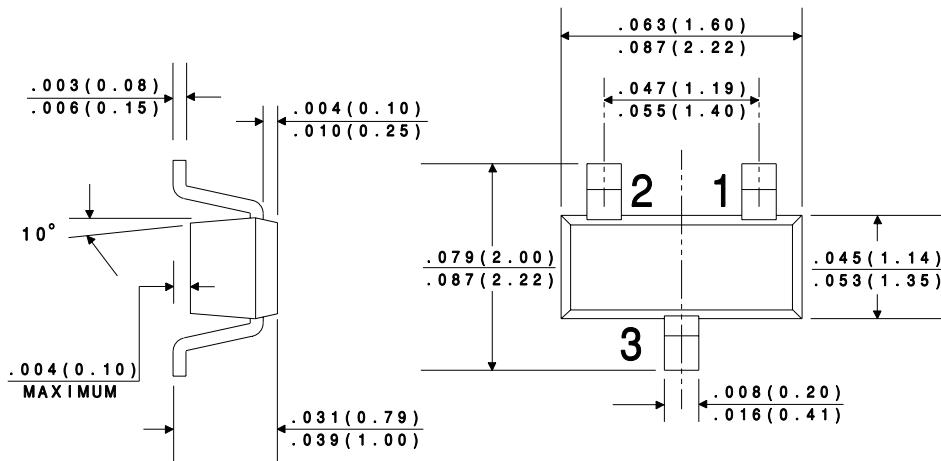
	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	60	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Collector Current	$I_C$	600	mA
Power Dissipation	$P_D$	250	mW
Operating and Storage			
Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance	$\Theta_{JA}$	500	$^{\circ}\text{C/W}$

### ELECTRICAL CHARACTERISTICS: ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$I_{CBO}$	$V_{CB}=50\text{V}$		10	nA
$I_{CBO}$	$V_{CB}=50\text{V}, T_A=125^{\circ}\text{C}$		10	$\mu\text{A}$
$I_{CEV}$	$V_{CE}=30\text{V}, V_{BE}=0.5\text{V}$		50	nA
$BV_{CBO}$	$I_C=10\mu\text{A}$	60		V
$BV_{CEO}$	$I_C=10\text{mA}$	60		V
$BV_{EBO}$	$I_E=10\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		0.4	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		1.6	V
$V_{BE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		1.3	V
$V_{BE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		2.6	V
$h_{FE}$	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	75		
$h_{FE}$	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	100		

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
$h_{FE}$	$V_{CE}=10V, I_C=10mA$	100		
$h_{FE}$	$V_{CE}=10V, I_C=150mA$	100	300	
$h_{FE}$	$V_{CE}=10V, I_C=500mA$	50		
$f_T$	$V_{CE}=20V, I_C=50mA, f=100MHz$	200		MHz
$C_{ob}$	$V_{CB}=10V, I_E=0, f=1.0MHz$		8.0	pF
$C_{ib}$	$V_{BE}=2.0V, I_C=0, f=1.0MHz$		30	pF
$t_{on}$	$V_{CC}=30V, V_{BE}=0.5, I_C=150mA, I_{B1}=15mA$		45	ns
$t_d$	$V_{CC}=30V, V_{BE}=0.5, I_C=150mA, I_{B1}=15mA$		10	ns
$t_r$	$V_{CC}=30V, V_{BE}=0.5, I_C=150mA, I_{B1}=15mA$		40	ns
$t_{off}$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		100	ns
$t_s$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		80	ns
$t_f$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		30	ns

All dimensions in inches (mm).



LEAD CODE:

- 1) BASE
- 2) EMITTER
- 3) COLLECTOR



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